General purpose transistor (dual transistors)

EMZ1 / UMZ1N / IMZ1A

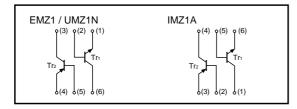
Features

- 1) Both a 2SA1037AK chip and 2SC2412K chip in a EMT or UMT or SMT package.
- 2) Mounting possible with EMT3 or UMT3 or SMT3 automatic mounting machines.
- 3) Transistor elements are independent, eliminating interference.
- 4) Mounting cost and area can be cut in half.

Structure

NPN / PNP epitaxial planar silicon transistor

●Equivalent circuit

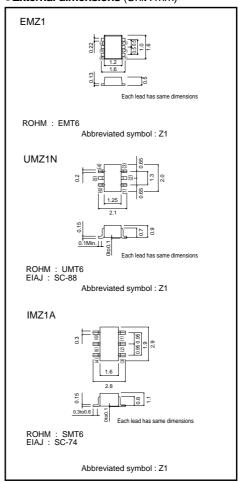


● Absolute maximum ratings (Ta = 25°C)

Parameter		Cumhal	Lin	l lmit	
		Symbol	Tr ₁	Tr ₂	Unit
Collector-base voltage		Vсво	60	-60	V
Collector-emitter voltage		Vceo	50	-50	V
Emitter-base voltage		VEBO	7	-6	V
Collector current		lc	150	-150	mA
Power	EMZ1, UMZ1N	Pc	150 (T	_* 1	
dissipation	IMZ1A	PC	300 (T	OTAL)	*2
Junction temperature		Tj	150		°C
Storage temperature		Tstg	-55 to +150		°C

- *1 120mW per element must not be exceeded.
- *2 200mW per element must not be exceeded.

●External dimensions (Unit : mm)



●Electrical characteristics (Ta = 25°C)

Tr₁ (NPN)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Collector-base breakdown voltage	ВУсво	60	_	-	V	Ic=50μA
Collector-emitter breakdown voltage	BVcEo	50	-	-	V	Ic=1mA
Emitter-base breakdown voltage	ВУево	7	-	-	V	I _E =50μA
Collector cutoff current	Ісво	_	_	0.1	μΑ	Vcb=60V
Emitter cutoff current	ІЕВО	-	-	0.1	μΑ	V _{EB} =7V
Collector-emitter saturation voltage	VCE (sat)	_	-	0.4	V	Ic/I _B =50mA/5mA
DC current transfer ratio	hfe	120	-	560	-	VcE=6V, Ic=1mA
Transition frequency	f⊤	-	180	-	MHz	Vc=12V, I=-2mA, f=100MHz
Output capacitance	Cob	_	2	3.5	PF	Vcb=12V, IE=0A, f=1MHz

Tr₂ (PNP)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Collector-base breakdown voltage	ВУсво	-60	-	-	V	Ic=-50μA
Collector-emitter breakdown voltage	BVcEo	-50	-	-	V	Ic=-1mA
Emitter-base breakdown voltage	ВУево	-6	-	-	V	I _E =-50μA
Collector cutoff current	Ісво	-	-	-0.1	μΑ	Vcb=-60V
Emitter cutoff current	ІЕВО	_	-	-0.1	μΑ	V _{EB} =-6V
Collector-emitter saturation voltage	VCE (sat)	-	-	-0.5	V	Ic/I _B =-50mA/-5mA
DC current transfer ratio	hfe	120	-	560	-	Vce=-6V, Ic=-1mA
Transition frequency	f⊤	-	140	-	MHz	Vce=-12V, Ie=2mA, f=100MHz
Output capacitance	Cob	_	4	5	PF	Vcb=-12V, Ie=0A, f=1MHz

Packaging specifications

	Package			
	Code	T2R	TR	T108
Туре	Basic ordering unit (pieces)	8000	3000	3000
EMZ1		0	_	_
UMZ1N		_	0	_
IMZ1A		_	_	0

•Electrical characteristic curves

Tr₁ (NPN)

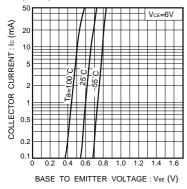


Fig.1 Grounded emitter propagation characteristics

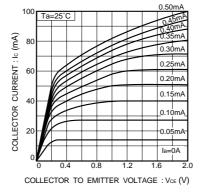


Fig.2 Grounded emitter output characteristics (I)

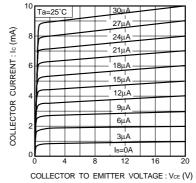


Fig.3 Grounded emitter output characteristics (II)



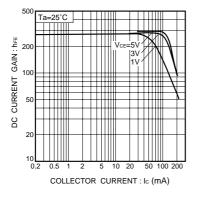


Fig.4 DC current gain vs. collector current (I)

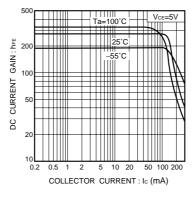


Fig.5 DC current gain vs. collector current (II)

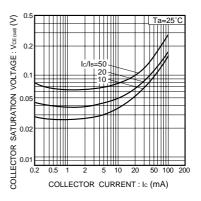


Fig.6 Collector-emitter saturation voltage vs. collector current (I)

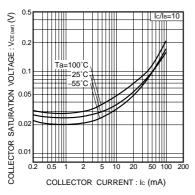


Fig.7 Collector-emitter saturation voltage vs. collector current (II)

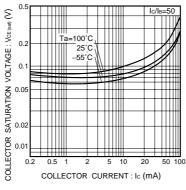


Fig.8 Collector-emitter saturation voltage vs. collector current (III)

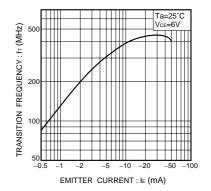


Fig.9 Gain bandwidth product vs. emitter current

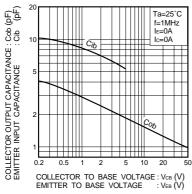


Fig.10 Collector output capacitance vs. collector-base voltage
Emitter input capacitance vs. emitter-base voltage

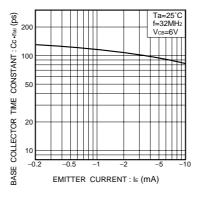


Fig.11 Base-collector time constant vs. emitter current

Tr₂ (PNP)

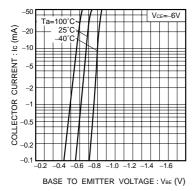


Fig.12 Grounded emitter propagation characteristics

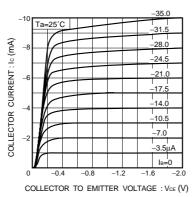


Fig.13 Grounded emitter output characteristics (I)

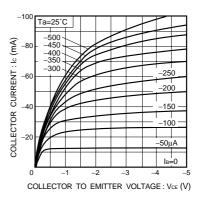


Fig.14 Grounded emitter output characteristics (II)

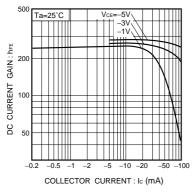


Fig.15 DC current gain vs. collector current (I)

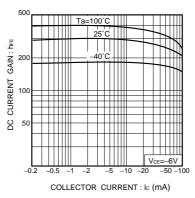


Fig.16 DC current gain vs. collector current (II)

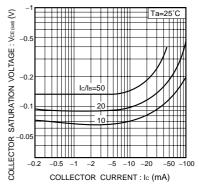


Fig.17 Collector-emitter saturation voltage vs. collector current (I)

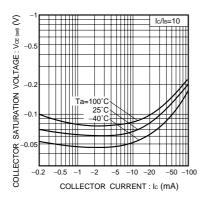


Fig.18 Collector-emitter saturation voltage vs. collector current (II)

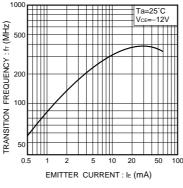


Fig.19 Gain bandwidth product vs. emitter current

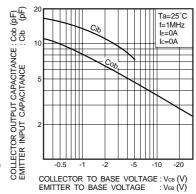


Fig.20 Collector output capacitance vs. collector-base voltage
Emitter input capacitance vs. emitter-base voltage

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